



SI4925BDY-T1-E3 Information



For Reference Only

Part Number SI4925BDY-T1-E3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2P-CH 30V 5.3A 8-SOIC **Package** 8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI4925BDY-T1-E3 Specifications

Manufacturer Part Number	SI4925BDY-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	2 P-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	5.3A
Rds On (Max) @ Id, Vgs	25 mOhm @ 7.1A, 10V
Vgs(th) (Max) @ Id	3V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	1.1W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

SI4925BDY-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4925BDY-T1-E3 Payment Methods



















SI4925BDY-T1-E3 Shipping Methods













If you have any question about SI4925BDY-T1-E3, please do not hesitate to contact us!

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